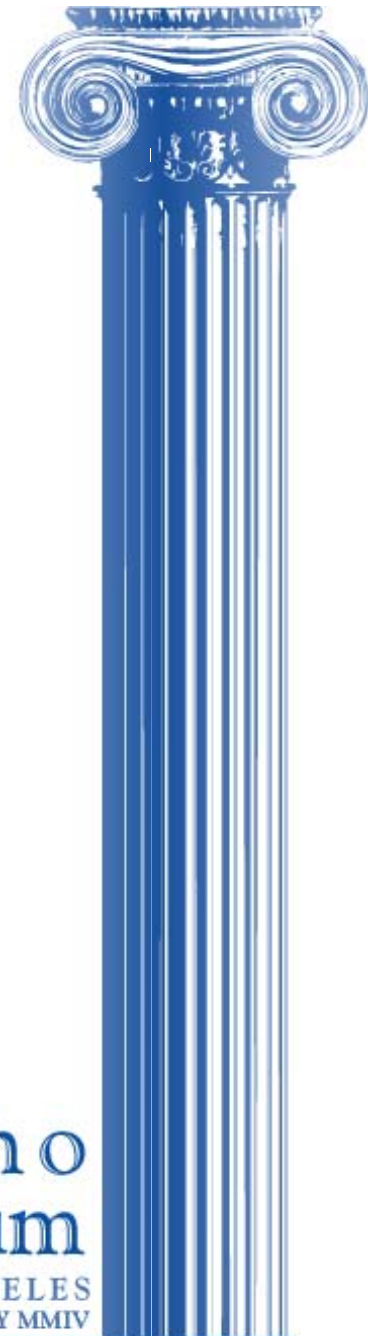


Cymer's Light Source Development for EUV Lithography

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Litho
Forum
LOS ANGELES
27-29 JANUARY MMIV

presented by
International SEMATECH



Outline

- **Introduction**
 - EUVL critical issues
 - EUV sources
- **Cymer Source Development**
 - Overview
 - Power scaling
- **Technology Outlook**

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Critical Issues Facing EUV Lithography

Industry Risk Perspective

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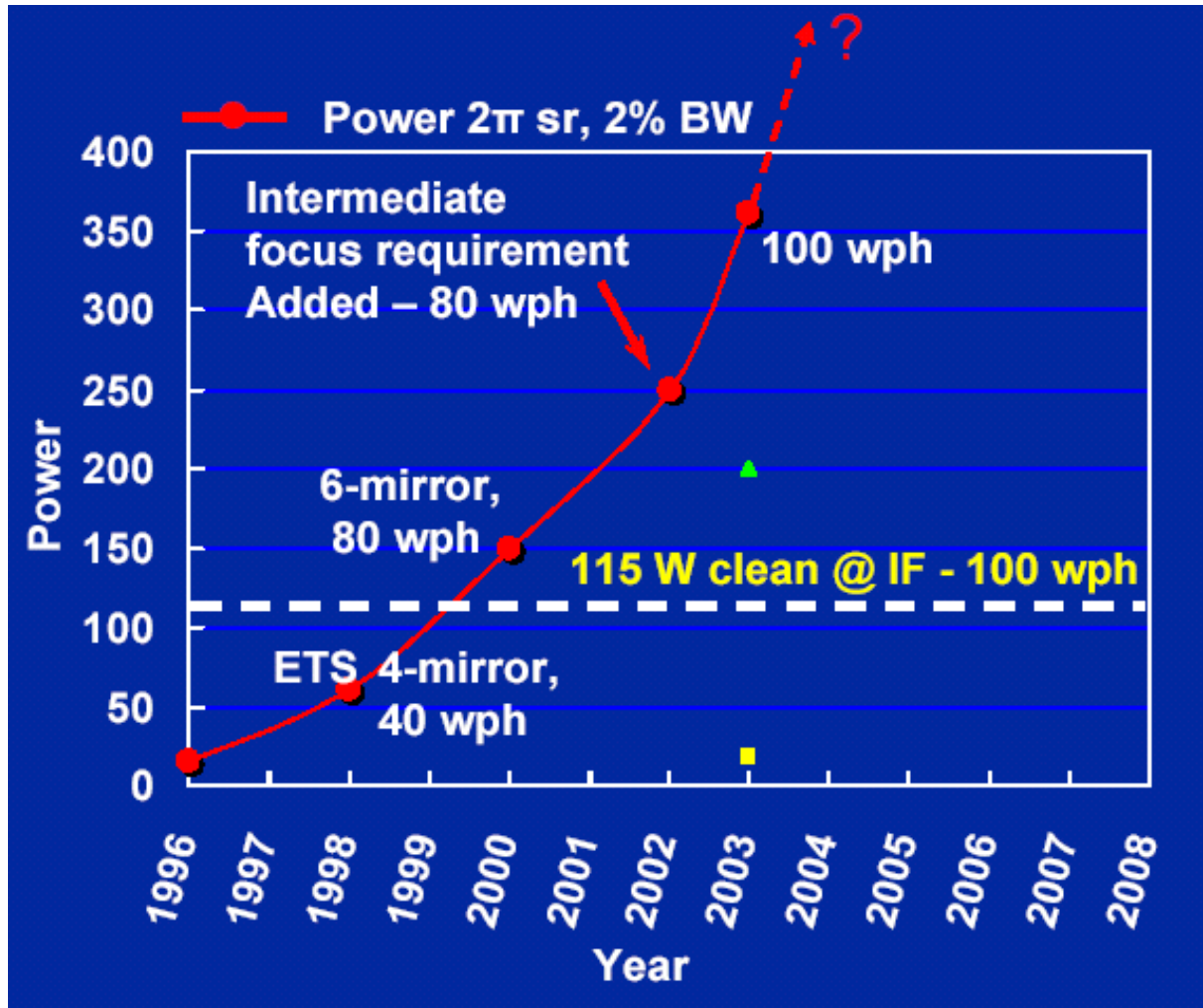
- Source output power and lifetime, including condenser optics lifetime (1,3)
- Availability of defect-free masks (2,5)
- Reticle protection during storage, handling and use (6)
- Projection and illuminator optics lifetime (7)
- Resist resolution, sensitivity and line width reduction (LWR) (10)
- Optics quality for the 32 nm node (8)

* 2002 ranking in brackets

Source: 2nd International EUVL Symposium Steering Committee, October 2003



Source Power Requirements Over Time



Source: C.Gwyn, 2nd Intl. EUVL Symposium, Oct. 2003

Industry and Tool Roadmap for EUVL

January 26, 2004 Press Release:

Subject: Development agreement between Intel and Cymer

Purpose: Accelerated development of production-worthy EUV source

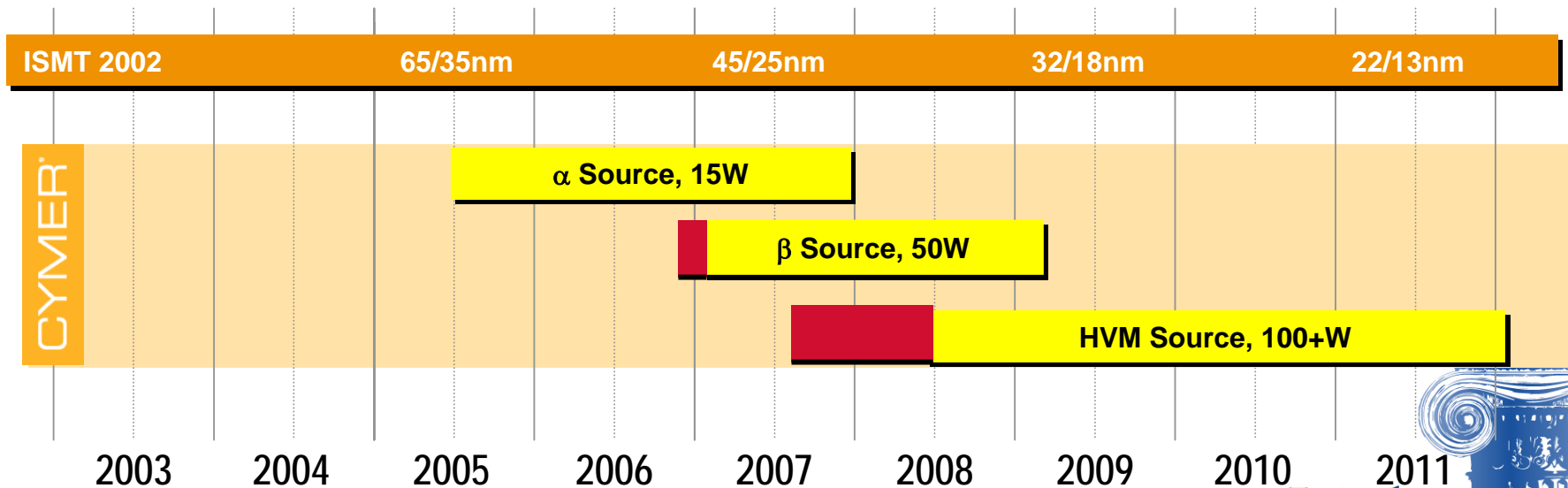
Amount: \$20M

Period: 3 Years

At this forum, Cymer makes the first public announcement of pursuing both DPP and LPP EUV light source technology.

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DRAM Half Pitch/MPU Gate Length



Choices for EUV Source Technology

The choice of EUV source technology can be broken into two major decisions:

1) Method of plasma excitation

Discharge Produced Plasma (DPP) or Laser Produced Plasma (LPP)

2) Source element

Xe, Sn, In, Li...

Problems to be Solved

The most significant problems that must be solved for any choice of EUV source technology:

- EUV power scaling: 100+W (in-band) at the intermediate focus
- Collector lifetime: 100 G shots
(A shorter collector lifetime can be tolerated if its cost is low and replacement time is short)
- System Affordability:

DPP: collector lifetime, electrode lifetime, debris shield lifetime

LPP: system price, collector lifetime, laser component lifetime

EUV Power Scaling: Source Element Choice

- Though xenon will remain a convenient source element during development, it will not likely be the High Volume Manufacturing (HVM) source element due to low conversion efficiency.
- The remaining candidates (with potentially higher CE) are condensable materials at room temperature.
 - Thus, improved CE comes with the new challenge of collector protection/cleaning of low vapor pressure source elements.

EUV Power Scaling: Source Multiplexing

- Since the DPP source etendue is equal to the allowed upper limit, combining multiple DPP sources requires temporal multiplexing with moving mirrors or sources.
- The LPP source etendue is much smaller than the allowed upper limit, thus multiple LPP sources can be combined optically.
 - EUV power scaling for LPP can be achieved by adding identical systems (for example: a 100W source can be made up of 2 X 50W sources).
 - Only the technology problems of a smaller power source must be solved for LPP (50W instead of full 100W).

EUV Power Scaling: Thermal Engineering

- **Electrode cooling is the greatest thermal challenge for DPP**
 - The technical path to provide the required thermal extraction to achieve 100+W at intermediate focus is very challenging.
- **Jet nozzle cooling was greatest thermal challenge for LPP**
 - With the development of liquid jet and droplet source delivery at large distances, nozzle cooling no longer an issue.
 - Thermal engineering challenge of LPP has “moved upstream” to the laser head – a more tractable challenge.

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Primary Collector Lifetime: Debris

- **DPP systems can produce the following types of debris:**
 - Fast source element ions
 - Fast source element neutrals
 - Source element particles
 - Fast electrode material ions
 - Fast electrode material neutrals
 - Electrode material particles
 - Insulator material
- **LPP systems can produce the following types of debris (assuming long distance source element delivery):**
 - Fast source element ions
 - Fast source element neutrals
 - Source element particles

Primary Collector Lifetime: Debris

- The primary difference between debris from DPP and LPP is the existence of DPP electrode and insulator material.
- DPP erosion tests show that tungsten is the best electrode material.
- Tungsten has a higher atomic mass than any proposed source element.
- Thus, regardless of source element choice the DPP must contend with high atomic mass debris.

System Affordability

Major components of EUV source system cost:

DPP

Grazing incidence collector
(multi shell)

Source vacuum vessel system

Electrodes with cooling

Source element delivery

SSPPM

Consumables

Collector

Electrodes

Debris trap

LPP

Multi-layer mirror collector
(single “element”)

Source vacuum vessel system

Beam delivery

Source element delivery

Laser source

Collector

Pump diodes / Laser chamber

Laser optics

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Why is Our Current Assessment Different than That Previous?

DPP

- Goal was 30-40W source at plasma point. Now goal is 100+W at intermediate focus. Thermal engineering supported 30-40W at plasma point, but questionable if it can support 100+W at intermediate focus.
- DPF produced small source size, but at low efficiency. As efficiency increased, so did source size.
- Efforts to reduce electrode erosion are yielding, but not quickly, and with a drop in optical efficiency.

LPP

- Long distance nozzles did not exist. Nozzle erosion was considered insurmountable.
- Diode laser prices and lifetimes needed much improvement.
- MOPA excimer did not exist. We had no practical path towards high power, high repetition rate excimer for LPP.

Cymer EUV Source Outlook

DPP

- DPP development ongoing

LPP

- Experiments with Nd:YAG laser at 1064, 532, 355, 266 nm
- Test standard pulse duration and shortened pulse duration 248 nm
- Improve laser beam quality (reduce spot size)
- Compare different targets: jet, droplet, pellet
- Target position control
- Quantify major mirror erosion mechanisms



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